Silicon Carbide Diode

Rev.02 - 13 June 2024

Product data sheet

1. General description

WeEn Sem

Dual Silicon Carbide Schottky diode in a 3-lead TO247 plastic package, designed for high frequency switched-mode power supplies.

RóHS) (Falogen-Free Lead-Free

2. Features and benefits

- Highly stable switching performance
- High forward surge capability I_{FSM}
- · Extremely fast reverse recovery time
- · Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant
- High junction operating temperature capability (T_{j(max)} = 175 °C)

3. Applications

- Power factor correction
 - Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

4. Quick reference data

	uick reference data						1
Symbol	Parameter	Conditions	Notes	s Values			Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage				1200		V
Io	limiting average forward current	T _{mb} ≤ 153 °C; DC; both diodes		20		А	
T _j	junction temperature			-55 to 175		°C	
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	I_F = 10 A; T_j = 25 °C; per diode; Fig. 5		-	1.42	1.60	V
		I_{F} = 10 A; T_{j} = 150 °C; per diode; <u>Fig. 5</u>		-	1.90	2.30	V
		I_{F} = 10 A; T _j = 175 °C; per diode; <u>Fig. 5</u>		-	2.00	2.50	V
Dynamic	characteristics						
Q _r	recovered charge	$I_F = 10 \text{ A}; \text{d} I_F/\text{d} t = 500 \text{ A}/\mu\text{s}; \text{V}_R = 400 \text{ V};$ $T_i = 25 ^\circ\text{C}; \text{ per diode; } \frac{\text{Fig. } 7}{2}$		-	22	-	nC

5. Pinning information

Table 2. P	inning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode		
2	К	cathode		
3	A2	anode		<u> </u>
mb	mb	mounting base; connected to cathode		sym125

6. Ordering information

Fable 3. Ordering information								
Type number Package		Orderable part number	Packing	Small packing	Package	Package		
	name		method	quantity	version	issue date		
WNSC2D201200CW	TO247	WNSC2D201200CW6Q	Tube	30	SOT429 (L)	25-Mar-2013		
					TO247P (P)	09-Mar-2023		

7. Marking

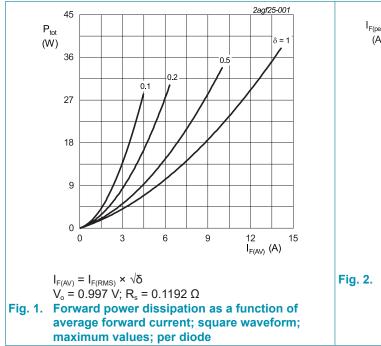
Table 4. Marking codes							
Type number	Marking codes						
WNSC2D201200CW	WNSC2D 201200CW						

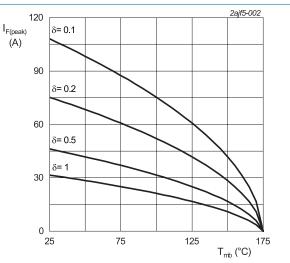
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

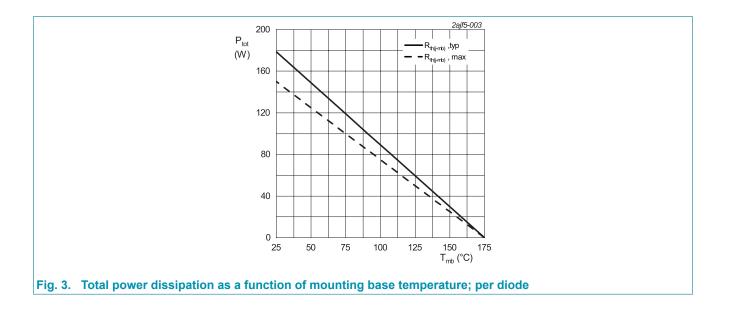
Symbol	Parameter	Conditions	Notes	Values	Unit
V _{RRM}	repetitive peak reverse voltage			1200	V
V_{RWM}	crest working reverse voltage			1200	V
V _R	reverse voltage	DC		1200	V
lo	limiting average forward	T _{mb} ≤ 153 °C; DC; both diodes		20	А
	current	T _{mb} ≤ 125 °C; DC; both diodes		33	А
		T _{mb} ≤ 25 °C; DC; both diodes		63	А
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 μs; T _{mb} ≤ 125 °C; square-wave pulse; per diode		25	A
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode		80	A
		t_p = 10 µs; $T_{j(init)}$ = 25 °C; square-wave pulse; per diode		750	A
l ² t	I ² t for fusing	sine-wave pulse; $T_{j(init)}$ = 25 °C; t_p = 10 ms		32	A ² s
T _{stg}	storage temperature			-55 to 175	°C
Tj	junction temperature			-55 to 175	°C





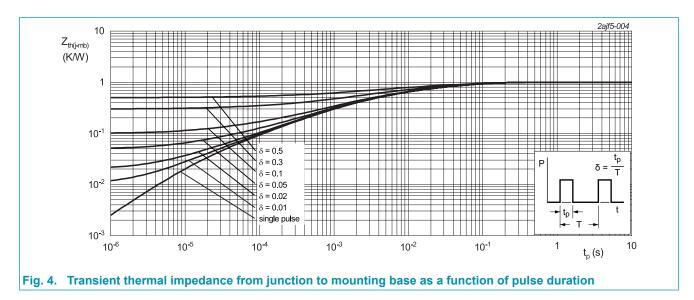


WNSC2D201200CW Silicon Carbide Diode



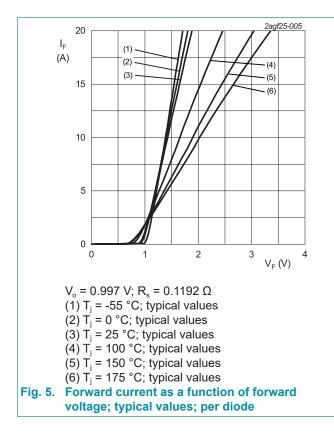
9. Thermal characteristics

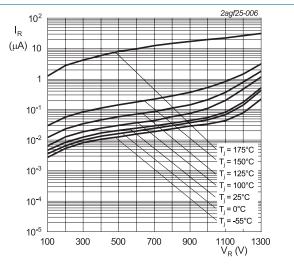
Table 6. Th	ermal characteristics						
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance	per diode; <u>Fig. 4</u>		-	0.84	1	K/W
	from junction to mounting base	both diodes conducting		-	0.45	0.55	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air		-	40	-	K/W



10. Characteristics

Table 7. Cl	naracteristics						
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static cha	racteristics						
$V_{\rm F}$	forward current	$I_{F} = 10 \text{ A}; T_{j} = 25 \text{ °C}; \text{ per diode}; Fig. 5$		-	1.42	1.60	V
		$I_{F} = 10 \text{ A}; T_{j} = 150 \text{ °C}; \text{ per diode}; Fig. 5$		-	1.90	2.30	V
		$I_{F} = 10 \text{ A}; T_{j} = 175 \text{ °C}; \text{ per diode}; Fig. 5$		-	2.00	2.50	V
I _R	reverse current	V_{R} = 1200 V; T _j = 25 °C; per diode; <u>Fig. 6</u>		-	1	50	μA
		V_{R} = 1200 V; T _j = 175 °C; per diode; <u>Fig. 6</u>		-	25	500	μA
Dynamic	characteristics						
Q _r	recovered charge	$I_F = 10 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A}/\mu\text{s};$ $T_j = 25 ^\circ\text{C}; \text{ per diode}; \frac{\text{Fig. 7}}{2}$		-	22	-	nC
C _d	diode capacitance	f = 1 MHz; V _R = 1 V; T _j = 25 °C		-	481	-	pF
		f = 1 MHz; V _R = 400 V; T _j = 25 °C		-	42	-	pF
		f = 1 MHz; V _R = 800 V; T _j = 25 °C		-	31	-	pF
E _{as}	non-repetitive avalanche energy	I_R = 4.2 A; L = 10 mH; $T_{j(init)}$ = 25 °C; per diode		88	-	-	mJ



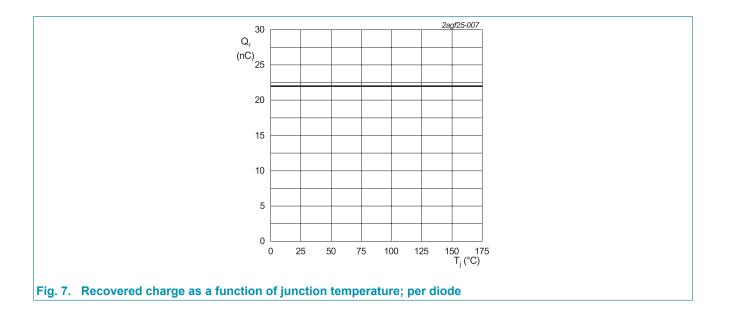




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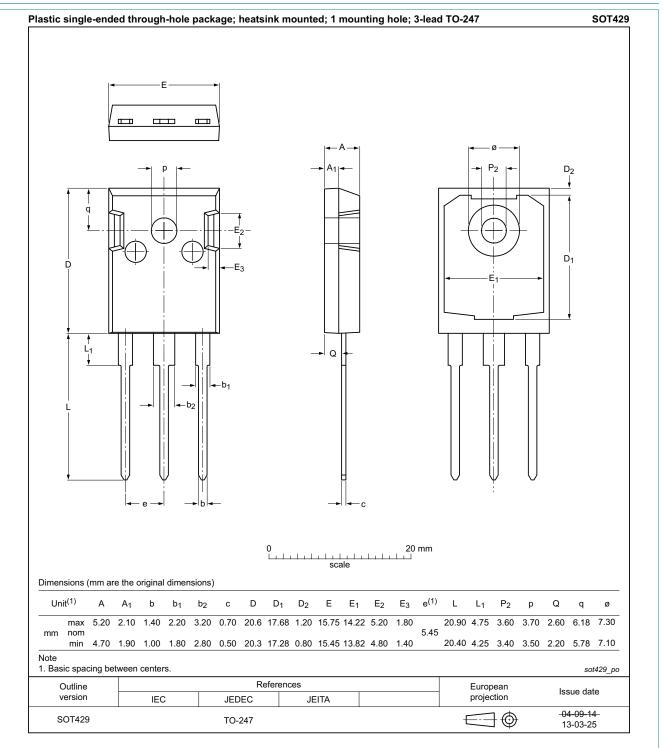
WNSC2D201200CW

Silicon Carbide Diode



Silicon Carbide Diode

11. Package outline



Silicon Carbide Diode

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or [1] completing a design.

- The term 'short data sheet' is explained in section "Definitions". [2]
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